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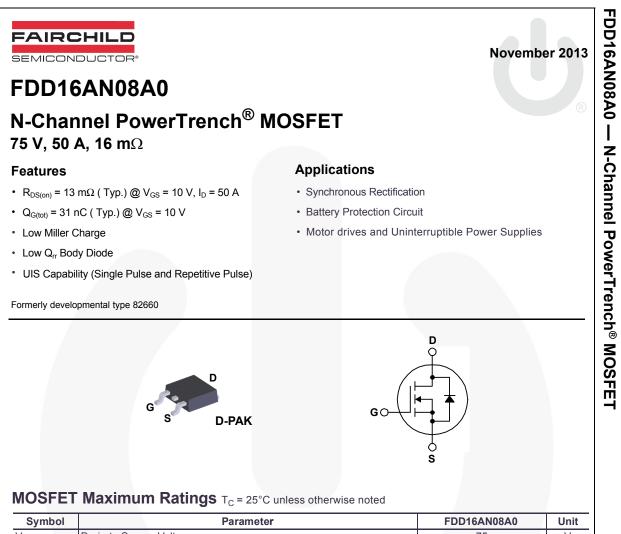
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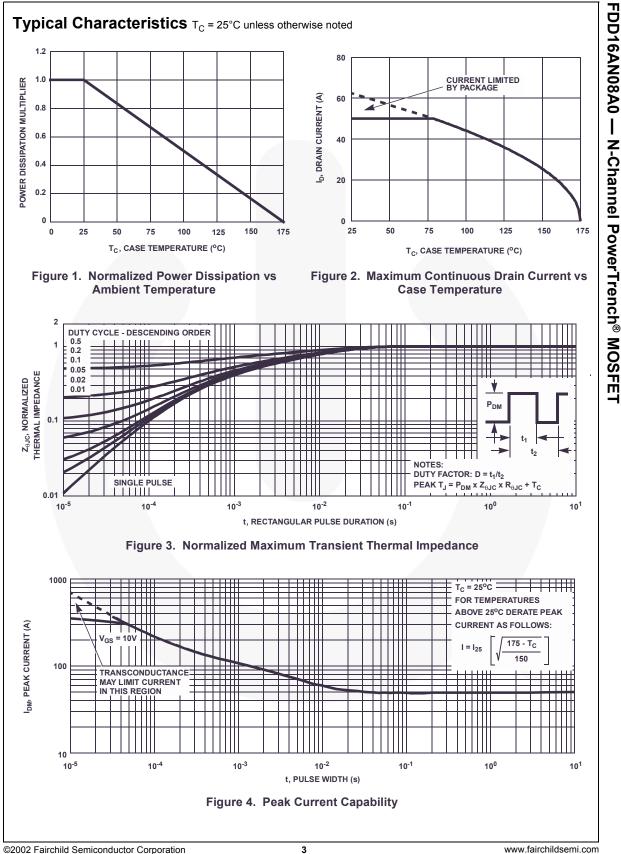
to Source Voltage to Source Voltage	75 ±20	V V	
0	±20	V	
Current			
inuous (T _C < 79 ^o C, V _{GS} = 10V)	50	А	
inuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$, with $R_{\theta JA} = 52^{\circ}C/W$)	9	Α	
ed	Figure 4	Α	
e Pulse Avalanche Energy (Note 1)	95	mJ	
er dissipation	135	W	
te above 25°C	0.9	W/ºC	
Operating and Storage Temperature -55 to 1			
	inuous ($T_C < 79^{\circ}$ C, $V_{GS} = 10$ V) inuous ($T_{amb} = 25^{\circ}$ C, $V_{GS} = 10$ V, with $R_{\theta JA} = 52^{\circ}$ C/W) ed e Pulse Avalanche Energy (Note 1) er dissipation te above 25^{\circ}C ating and Storage Temperature	inuous ($T_{amb} = 25^{\circ}C$, $V_{GS} = 10V$, with $R_{\theta JA} = 52^{\circ}C/W$)9edFigure 4e Pulse Avalanche Energy (Note 1)95er dissipation135te above $25^{\circ}C$ 0.9	

Thermal Characteristics

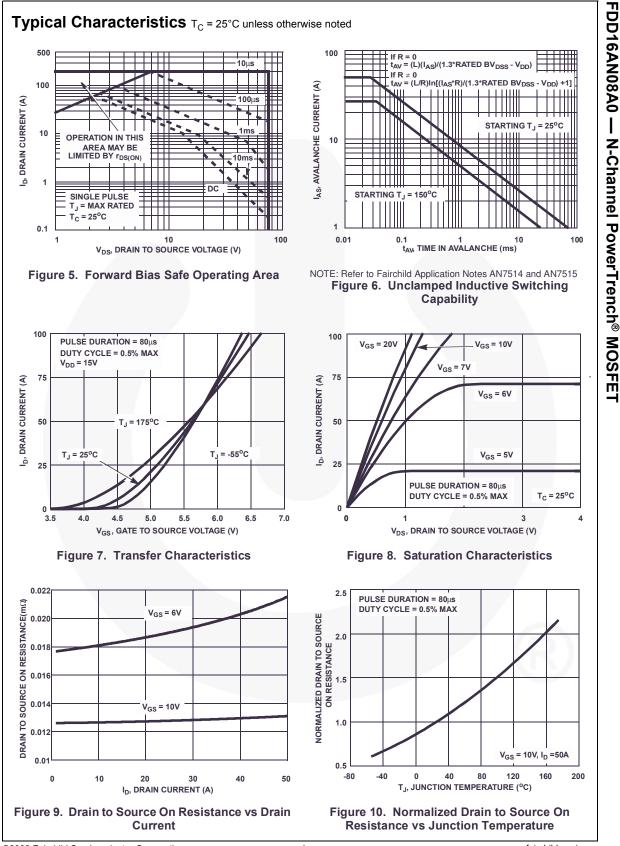
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	1.11	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	100	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, 1in ² copper pad area, Max.	52	°C/W

1

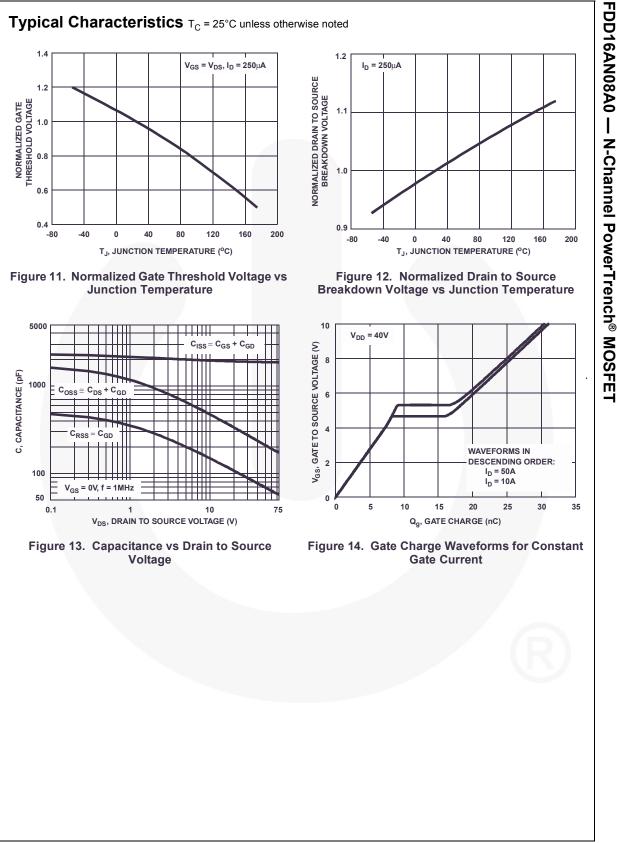
Device MarkingDeviceFDD16AN08A0FDD16AN08A0		Package	Package Reel Size		Vidth	Quar	ntity	
		D-PAK 330 mm		16 mm		2500 units		
Electric	al Char	acteristics T _c = 25°C	unless otherwis	se noted				
Symbol	Parameter Test Conditions		Min	Тур	Max	Unit		
Off Chara	acteristic	s						
B _{VDSS}		-	$I_{\rm p} = 250 \mu A$	$V_{oo} = 0V$	75	-	-	V
PVDSS	Drain to Source Breakdown Voltage		$I_D = 250\mu A, V_{GS} = 0V$ $V_{DS} = 60V$		-	-	1	v
I _{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V$	T _C = 150°C	-	-	250	μA	
I _{GSS}	Gate to Se	ource Leakage Current	$V_{GS} = \pm 20V$	1.0 .00 0	-	-	±100	nA
	1		-63			1		
On Chara	octeristics	S						
V _{GS(TH)}	Gate to Se	ource Threshold Voltage	$V_{GS} = V_{DS}$,	l _D = 250μA	2	-	4	V
			I _D = 50A, V _C	_{ss} = 10V	-	0.013	0.016	
r	Drain to S	ource On Resistance	I _D = 25A, V _C	_{SS} = 6V	-	0.019	0.029	Ω
r _{DS(ON)}	Drain to 3	ource on Resistance	I _D = 50A, V _C T _J = 175 ^o C	_{iS} = 10V,	-	0.032	0.037	52
Dynamic	Characte	eristics						1
C _{ISS}	Input Cap	acitance			-	1874	-	pF
C _{OSS}	Output Ca			$V_{\rm DS}$ = 25V, $V_{\rm GS}$ = 0V,		290	-	pF
C _{RSS}		ransfer Capacitance	f = 1MHz		-	91	-	pF
Q _{g(TOT)}		Charge at 10V	V _{GS} = 0V to	10V		31	47	nC
Q _{g(TH)}		Gate Charge		2V _{VDD} = 40V	-	4	6	nC
Q _{gs}		ource Gate Charge		$I_{\rm D} = 50A$	-	9.7	-	nC
Q _{gs2}		rge Threshold to Plateau		I _g = 1.0mA	-	5.7	-	nC
Q _{gd}		rain "Miller" Charge			-	7.2	-	nC
	g Charac	teristics (V _{GS} = 10V)						
t _{on}	Turn-On T				-	-	93	ns
t _{d(ON)}	Turn-On D	elay Time				8	-	ns
t _r	Rise Time		V _{DD} = 40V, I	_D = 50A	-	54	- /	ns
t _{d(OFF)}	Turn-Off D	Delay Time	$V_{GS} = 10V,$		-	32	-	ns
t _f	Fall Time				-	22	-	ns
t _{OFF}	Turn-Off T	ïme			-	-	81	ns
	-	le Characteristics	-		<u>I</u>	-		
V _{SD}	T	Drain Diode Voltage	I _{SD} = 50A		-	-	1.25	V
			I _{SD} = 25A		-	-	1.0	V
t _{rr}		Recovery Time	$I_{SD} = 50A$, $dI_{SD}/dt = 100A/\mu s$		-	-	34	ns
Q _{RR}	Reverse F	Recovered Charge	I _{SD} = 50A, d	I _{SD} /dt = 100A/μs	-	-	31	nC

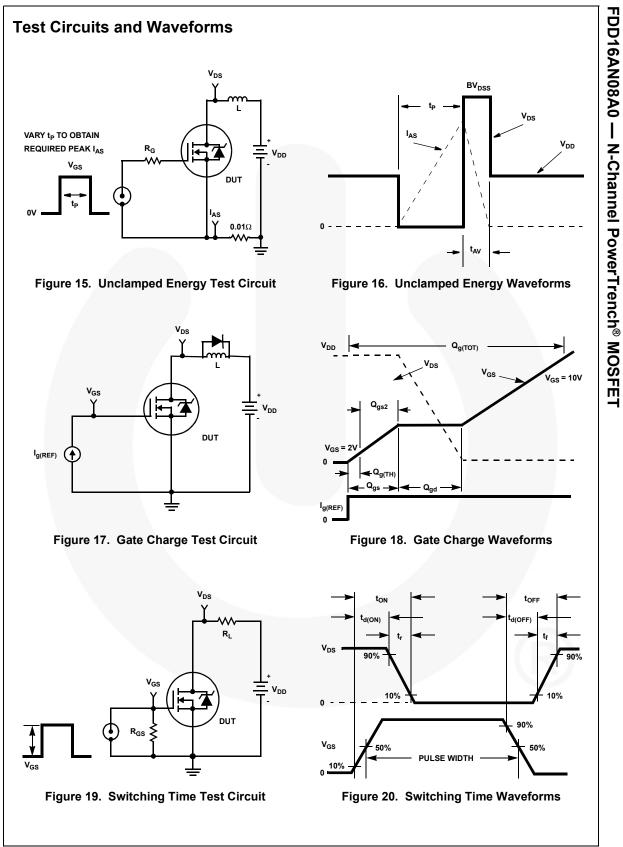


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Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature, T_{JM} , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation, P_{DM} , in an application. Therefore the application's ambient temperature, T_A (°C), and thermal resistance $R_{\theta JA}$ (°C/W) must be reviewed to ensure that T_{JM} is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-252 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of P_{DM} is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the $R_{\theta JA}$ for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 10z copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

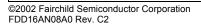
Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

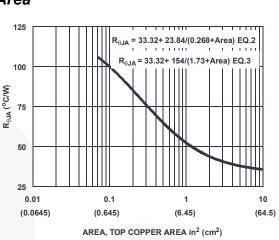
$$R_{\theta JA} = 33.32 + \frac{23.84}{(0.268 + Area)}$$
 (EQ. 2)

Area in Inches Squared

$$R_{\theta JA} = 33.32 + \frac{154}{(1.73 + Area)}$$
 (EQ. 3)

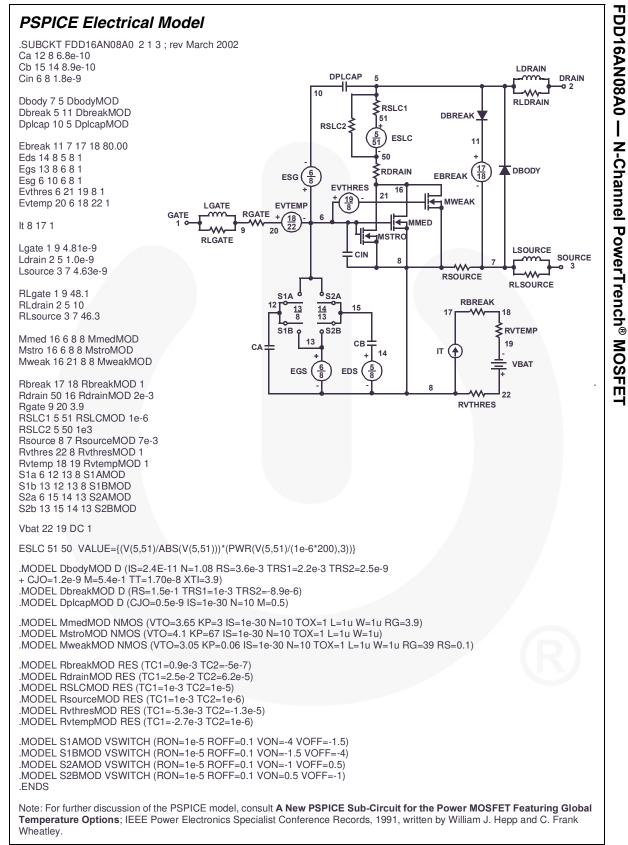
Area in Centimeters Squared





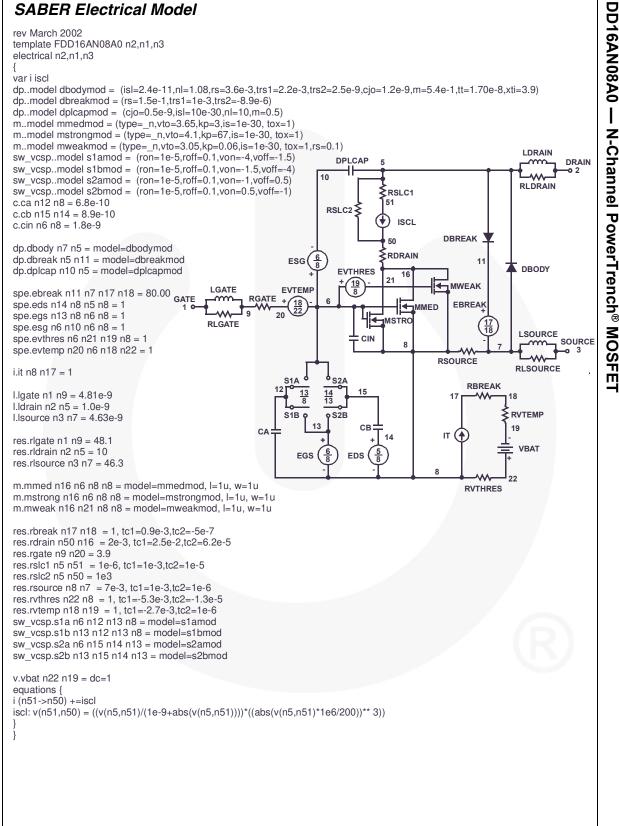


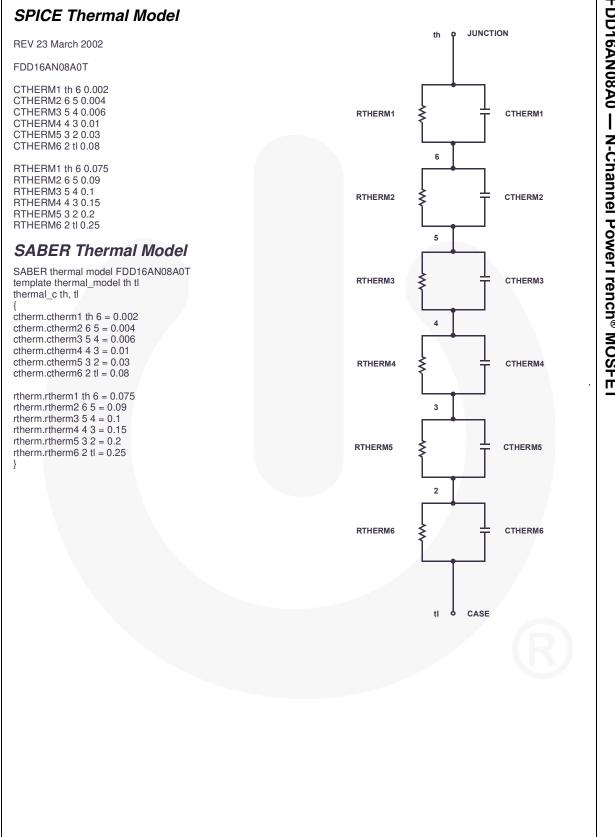
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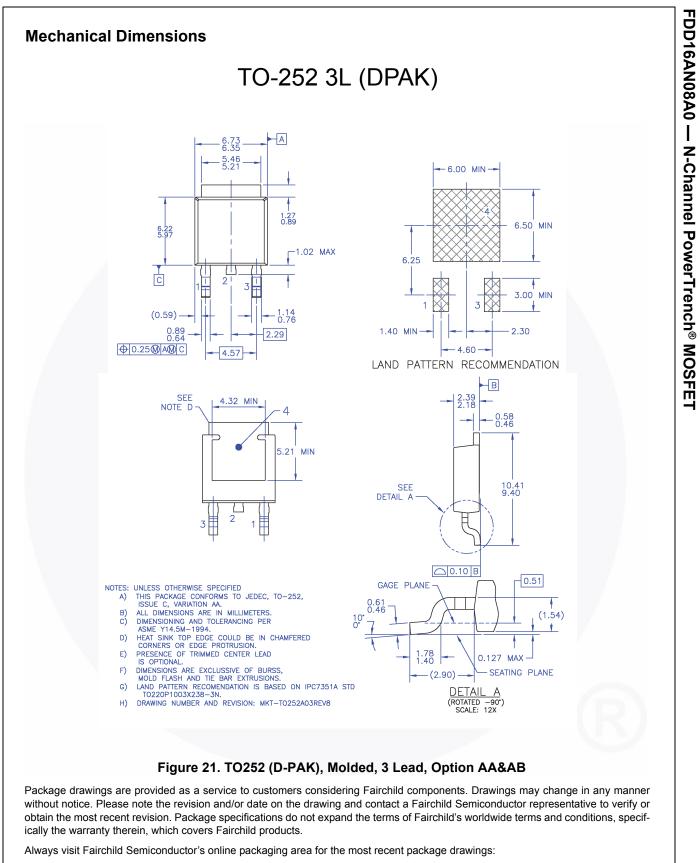


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SABER Electrical Model







http://www.fairchildsemi.com/package/packageDetails.html?id=PN_TT252-003

Dimension in Millimeters



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